



PATENT
Docket No.: ACT-307DVA

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Art Unit: 2814

Examiner: Mai, Anh D.

Serial No.: 10/036,303

Filed: December 28, 2001

In Re Application of: Hawley, et al.

For: METHOD FOR FABRICATING AN MOS TRANSISTOR HAVING
IMPROVED TOTAL RADIATION-INDUCED LEAKAGE CURRENT

Certificate of Mailing

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail, in an envelope addressed to MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450,

on 5/27/03

Signed

Martha N. Griffin

Martha N. Griffin

REQUEST FOR EXTENSION OF TIME

MS Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Applicant requests an extension of time of two month to respond to the Office Action of December 26, 2002. Enclosed is the requisite fee of \$410.00 as calculated pursuant to 37 C.F.R. §1.17(a-c) below:

One month extension
Two month extension
Three month extension

Small Entity

☐ \$ 55.00
☐ \$205.00
☐ \$465.00

Std. Fee

☐ \$ 110.00
☒ \$ 410.00
☐ \$ 930.00

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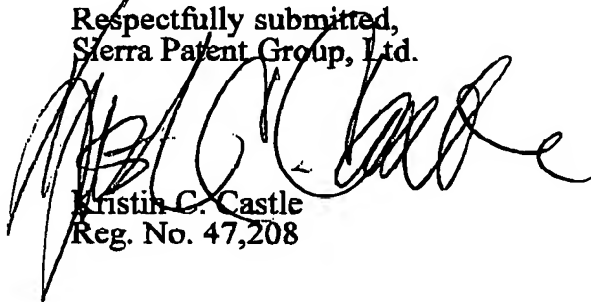
The Assistant Commissioner is hereby authorized to charge any additional fees or credit any overpayment to Deposit Account No.: 50-0612.

Dated:

5/22/03

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Respectfully submitted,
Sierra Patent Group, Ltd.



Kristin C. Castle
Reg. No. 47,208